

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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priority Application Serial No
priority Filing Date August 7, 2000
Inventor Gurtej S. Sandhu et al.
Assignee Micron Technology, Inc.
priority Group Art Unit
priority Examiner Laura M. Schillinger
Attorney's Docket No MI22-1897
Title: Methods of Forming Transistors (As Amended)

PRELIMINARY AMENDMENT

To:Box Patent Application

Assistant Commissioner for Patents

Washington, D.C. 20231

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In the Specification

Replace the title with -- Methods of Forming Transistors--.

At page 1, before the "Technical Field" section, please insert:

-- CROSS REFERENCE TO RELATED APPLICATION

This patent resulted from a divisional application of U.S. Patent

Application Serial No. 09/633,556, which was filed on August 7, 2000 .--.

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